

isc Silicon NPN Power Transistor

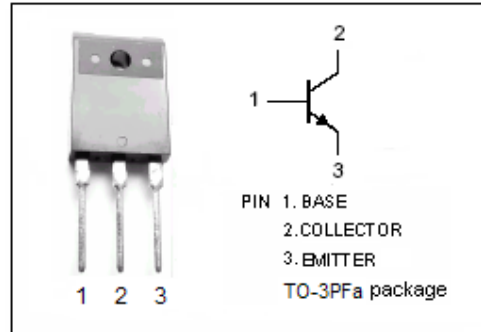
2SC3527

DESCRIPTION

- Low Collector Saturation Voltage
- High Collector Current
- Good Linearity of h_{FE}

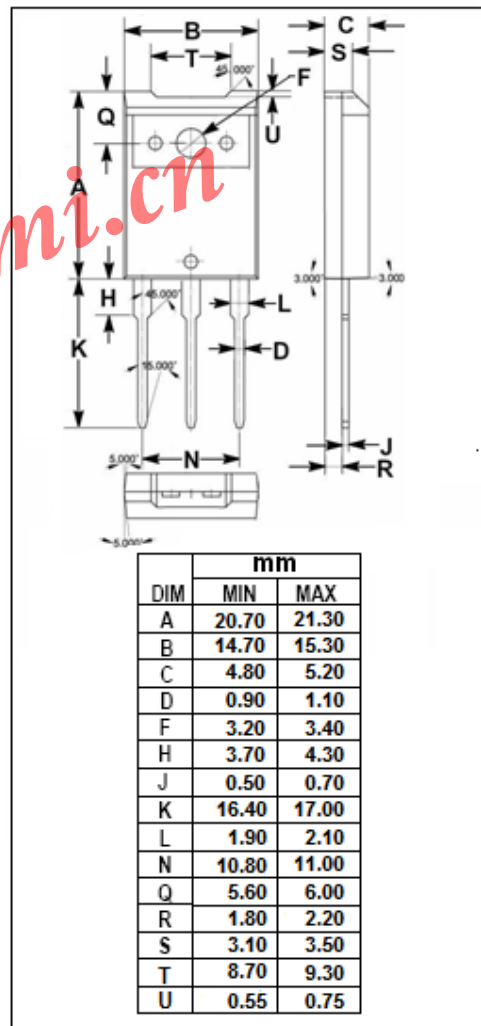
APPLICATIONS

- Designed for switching regulator and high voltage switching applications.



ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}C$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|---|---------|-------------|
| V_{CBO} | Collector-Base Voltage | 500 | V |
| V_{CEO} | Collector-Emitter Voltage | 400 | V |
| V_{EBO} | Emitter-Base voltage | 7 | V |
| I_C | Collector Current-Continuous | 15 | A |
| I_{CM} | Collector Current-Peak | 25 | A |
| I_B | Base Current-Continuous | 6 | A |
| P_C | Collector Power Dissipation @ $T_C=25^{\circ}C$ | 100 | W |
| | Collector Power Dissipation @ $T_a=25^{\circ}C$ | 3 | |
| T_J | Junction Temperature | 150 | $^{\circ}C$ |
| T_{stg} | Storage Temperature Range | -55~150 | $^{\circ}C$ |



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ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------|--------------------------------------|---|-----|------|-----|---------------|
| $V_{CEO(SUS)}$ | Collector-Emitter Sustaining Voltage | $I_C=0.5\text{A}; L=25\text{mH}$ | 400 | | | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $I_C=7\text{A}; I_B=1.4\text{A}$ | | | 1.0 | V |
| $V_{BE(sat)}$ | Base-Emitter Saturation Voltage | $I_C=7\text{A}; I_B=1.4\text{A}$ | | | 1.5 | V |
| I_{CBO} | Collector Cutoff Current | $V_{CB}=500\text{V}; I_E=0$ | | | 100 | μA |
| I_{EBO} | Emitter Cutoff Current | $V_{EB}=7\text{V}; I_C=0$ | | | 100 | μA |
| h_{FE-1} | DC Current Gain | $I_C=2\text{A}; V_{CE}=5\text{V}$ | 15 | | | |
| h_{FE-2} | DC Current Gain | $I_C=7\text{A}; V_{CE}=5\text{V}$ | 10 | | | |
| f_T | Current-Gain—Bandwidth Product | $I_C=1\text{A}; V_{CE}=10\text{V}; f=1\text{MHz}$ | | 15 | | MHz |

Switching times

| | | | | | | |
|-----------|--------------|--|--|--|-----|---------------|
| t_{on} | Turn-On Time | $I_C=7\text{A}; I_{B1}=1.4\text{A}, I_{B2}=-1.4\text{A}; V_{CC}=125\text{V}$ | | | 1.0 | μs |
| t_{stg} | Storage Time | | | | 2.5 | μs |
| t_f | Fall Time | | | | 1.0 | μs |